

Transport Criticality near the Mott Transition



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in collaboration with



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"Novel State of Matter Induced by Frustration"

Motivation

(A) What is unconventional behavior of **frustrated electron systems**?

- **Mott transition** is a metal-insulator transition not accompanied by any symmetry breaking and **spin frustration** is essential to it.

What is characteristic to Mott transition?

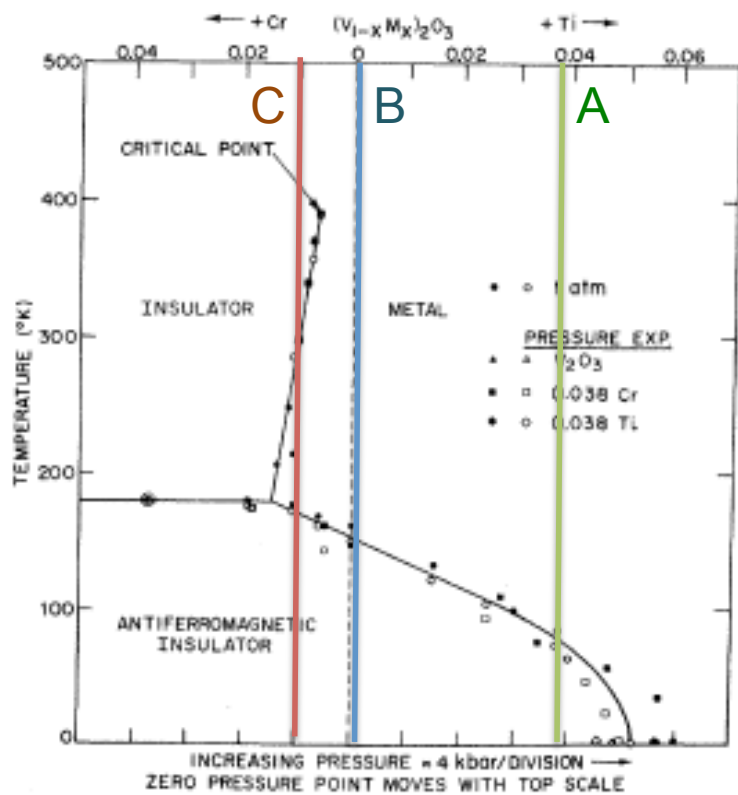
(B) Mystery in experimental works on singular electric conductivity near the Mott transition



Let us try direct numerical calculations of electric conductivity near the Mott transition and determine its critical exponent

[Ref: Sato, Hattori and Tsunetsugu, J. Phys. Soc. Jpn. **81**, 083703 (2012);
full paper submitted to Phys. Rev. B]

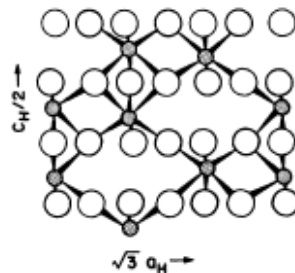
V₂O₃ – Mott insulator



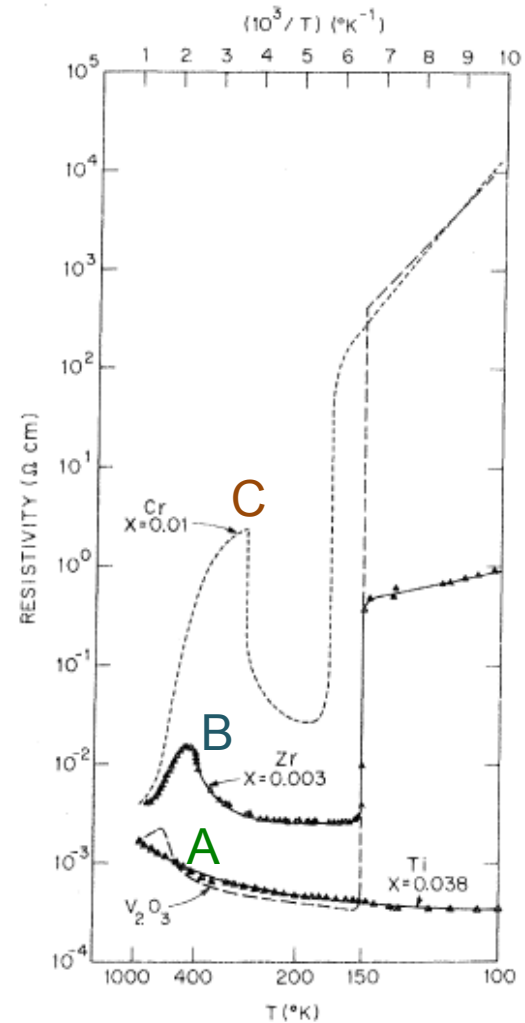
[McWhan et al, (1971, 1973)]

Transition from PMI to PMM

- Strongly correlated metal
- large specific heat
- large susceptibility

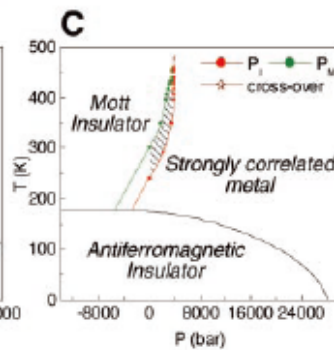
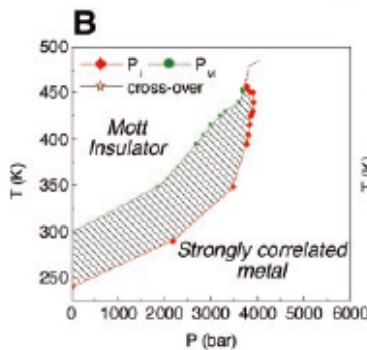
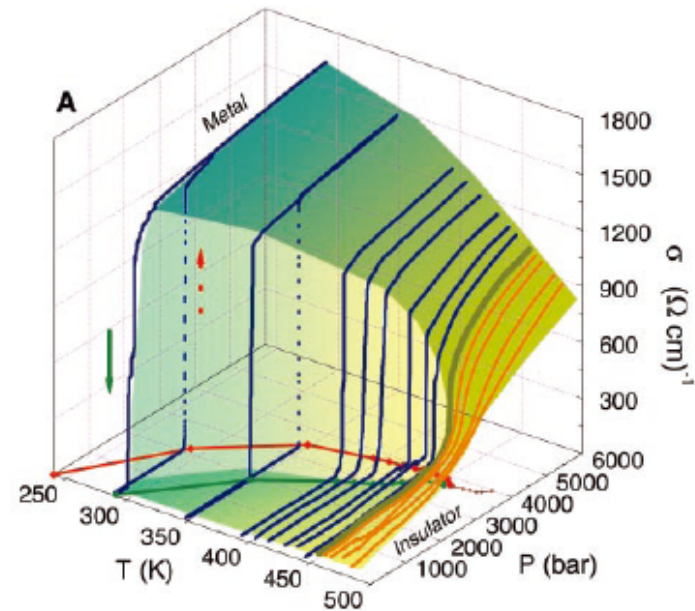


Electric resistivity

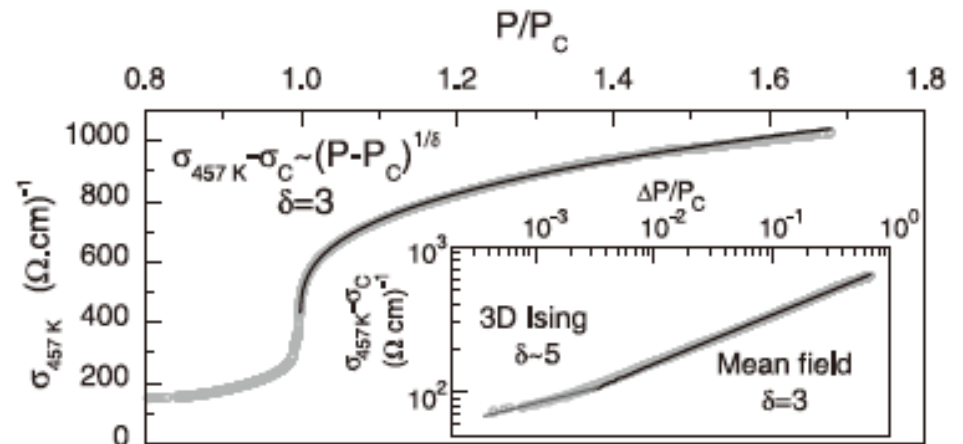


→ low T

V₂O₃ – DC conductivity at T_c



[Limelette et al, Science (2003)]



Mott metal-insulator transition takes place inside the paramagnetic region, and is **not accompanied by any symmetry breaking**.

This is similar to **liquid-gas transition**, which belongs to **Ising universality class**.

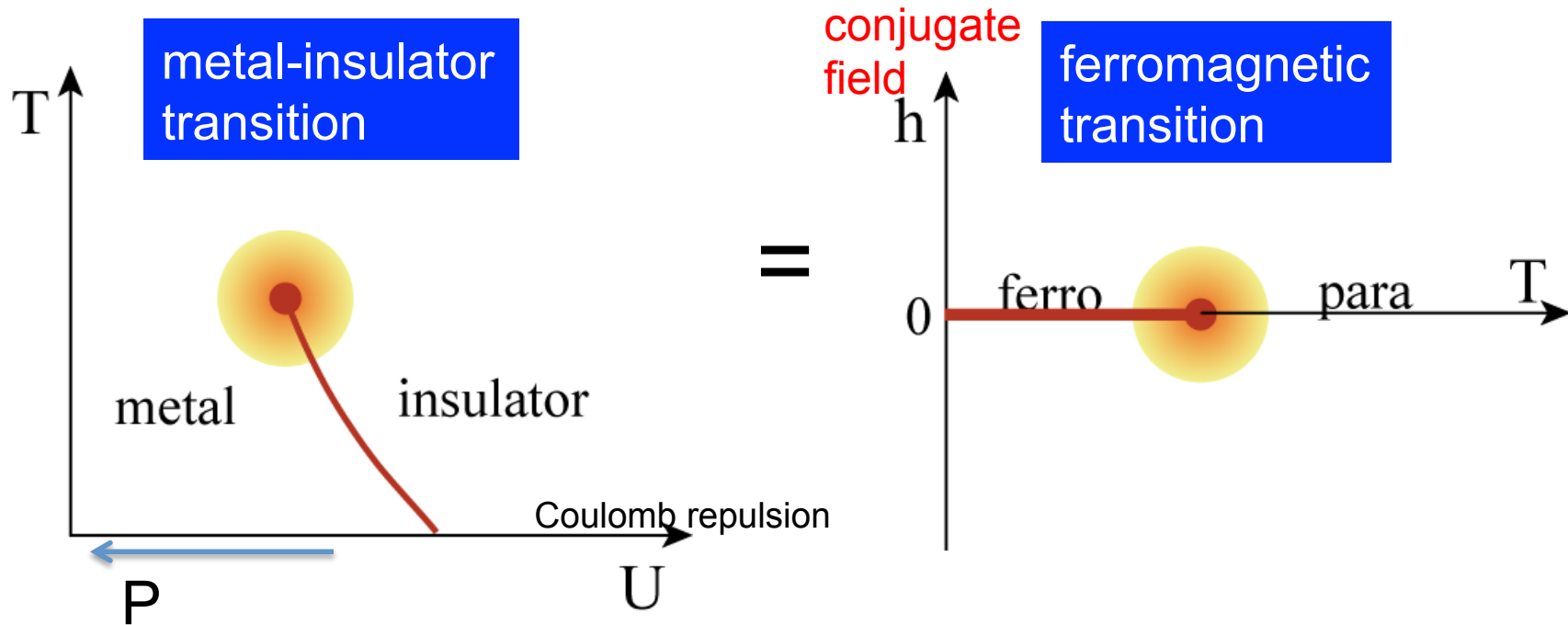
Observe Ising criticality in $\sigma(T,P)$

$$\Delta\sigma \sim |\Delta P|^{1/\delta}$$

$$1/\delta = 1/3 \rightarrow 1/5 \text{ crossover}$$

Mott transition: Ising universality class

double occupancy d is the order parameter of Mott transition
 → scalar ϕ^4 field theory → Ising universality class



correspondence

$d, \delta\sigma?$	m
δT	δT
$\delta U, -\delta P$	h

Scaling

◆ Ferromagnetic transition

$$m(\delta T, h) = |h|^{1/\delta} f\left(\frac{h}{|\delta T|^{\delta\beta}}\right)$$

$$m = |h|^{1/\delta} \quad (\text{at } T = T_c)$$

$$\Delta m = |\delta T|^\beta \quad (T < T_c)$$

◆ Metal-insulator transition (naive expectation)

$$\sigma(\delta T, \delta U) - \sigma_c \approx \sigma_{\text{sing}}(\delta T, \delta U) = |\delta U|^{1/\delta} f\left(\frac{\delta U}{|\delta T|^{\delta\beta}}\right)$$

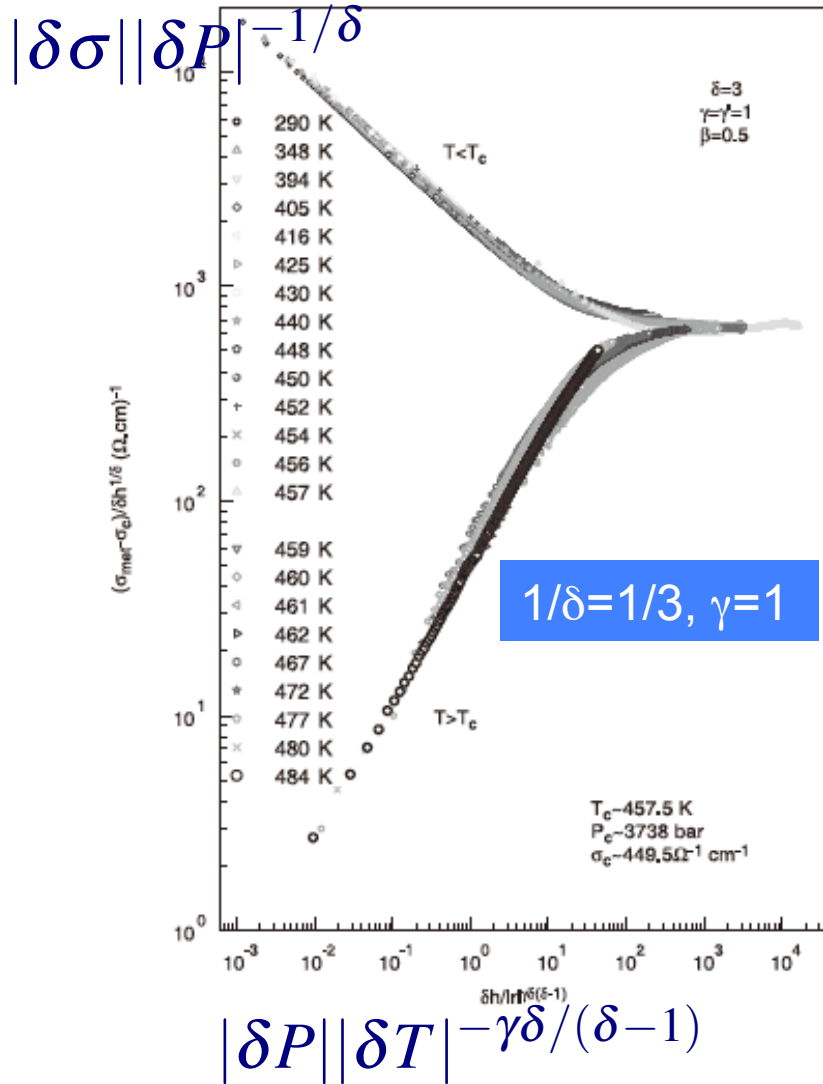
$$\Delta\sigma = |\delta U|^{1/\delta} \quad (\text{at } T = T_c)$$

$$\Delta\sigma = |\delta T|^\beta \quad (T < T_c)$$

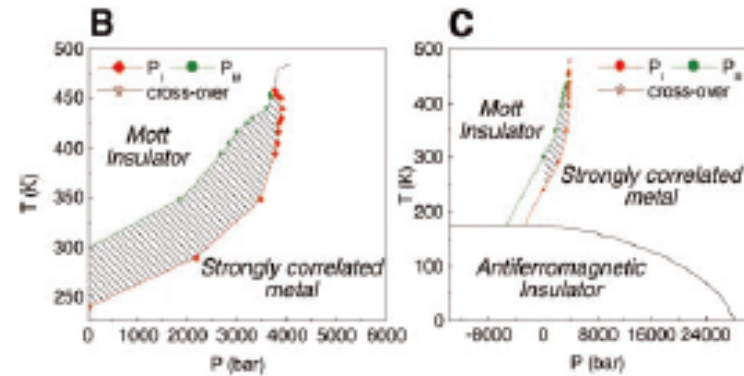
scaling relation $\gamma = \beta(\delta - 1)$

V₂O₃ - Scaling of DC conductivity

[Limelette et al, Science (2003)]



more systematic scaling



$$\delta U = -\delta P$$

$$\sigma(\delta T, \delta U) - \sigma_c = |\delta U|^{1/\delta} f\left(\frac{\delta U}{|\delta T|^{\gamma\delta/(\delta-1)}}\right)$$

$$\delta\sigma \sim -|\delta U|^{1/\delta} \text{sgn}\delta U \quad (\text{at } T = T_c)$$

Basic Hypothesis behind this scaling

This kind scaling analysis is based on an implicit assumption that conductivity is a regular function of the order parameter in the vicinity of the critical end point.

$$\sigma(T,U) = \sigma_{\text{regular}} + \sigma_{\text{singular}}$$

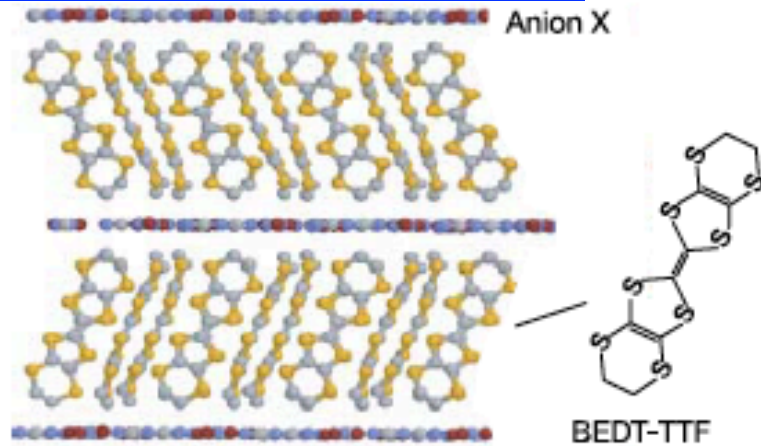
$$\sigma_{\text{singular}}(\delta T, \delta U) = A_1 \langle d(\delta T, \delta U) \rangle + A_2 \langle d(\delta T, \delta U)^2 \rangle + \dots$$

order parameter

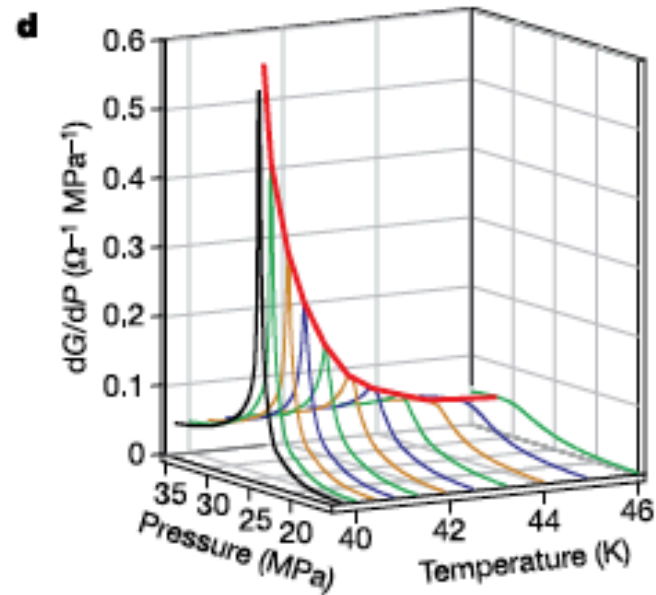
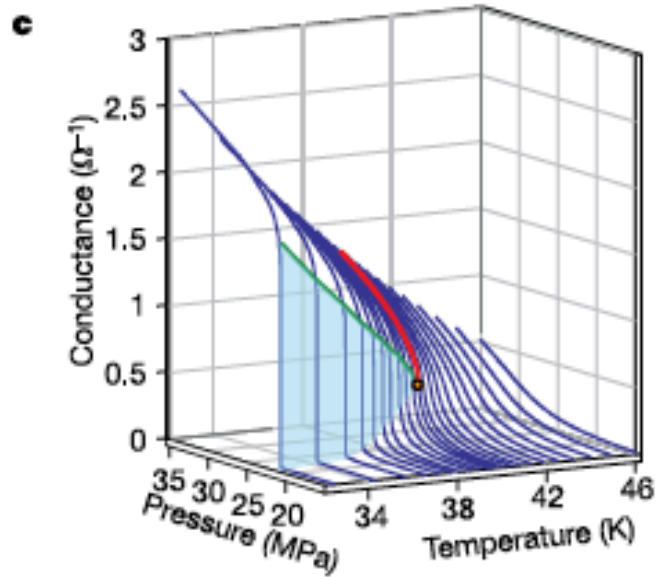
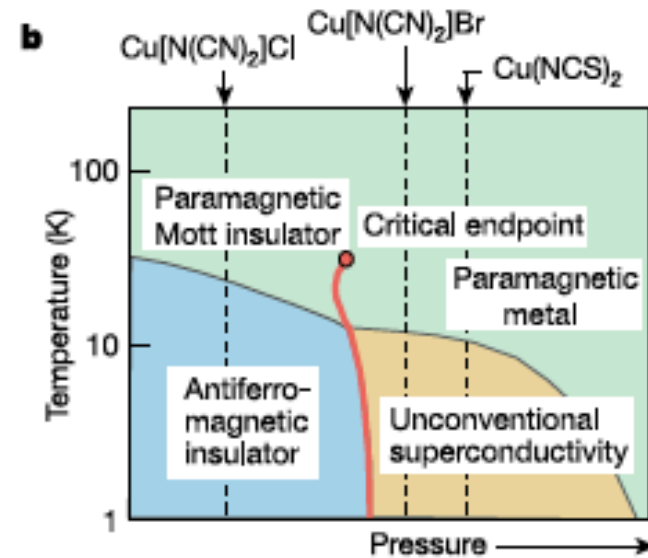
However, this is highly nontrivial.

κ -type organic – DC conductivity

triangular lattice of ET dimers

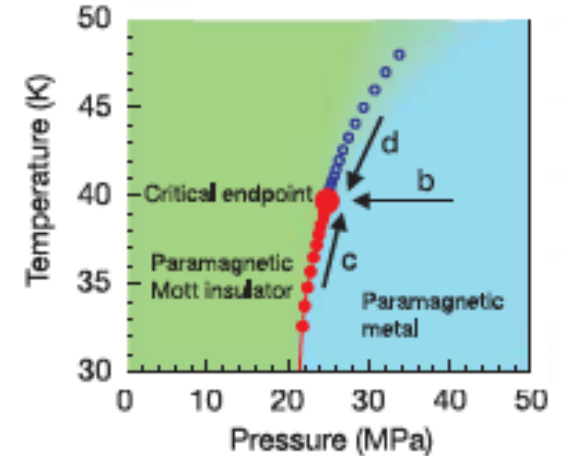
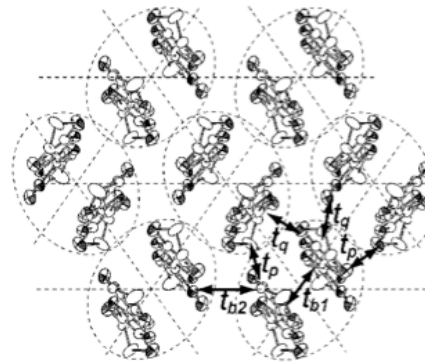
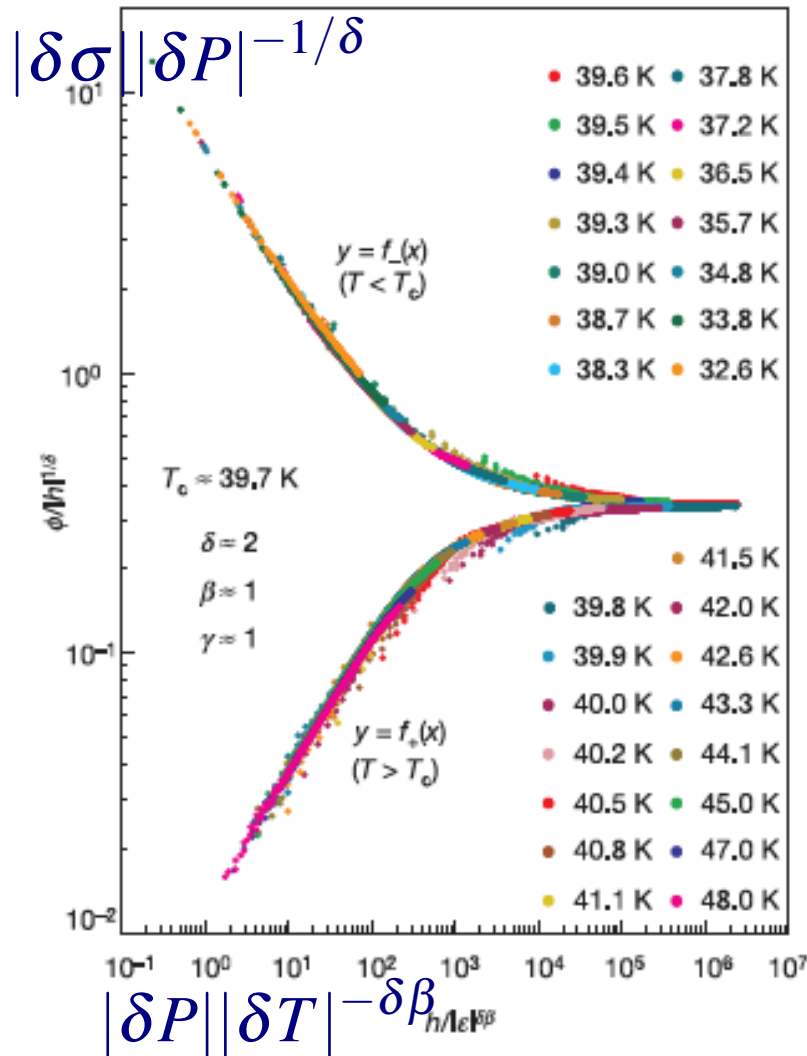


κ -(ET)₂Cu[N(CN)₂]Cl



κ -type organic - Scaling of DC conductivity

[Kagawa et al, Nature (2005)]



$$\delta U = -\delta P$$

$$\sigma(\delta T, \delta U) - \sigma_c = |\delta U|^{1/\delta} f\left(\frac{\delta U}{|\delta T|^{\delta\beta}}\right)$$

$$\delta\sigma \sim -|\delta U|^{1/\delta} \text{sgn}\delta U \quad (\text{at } T = T_c)$$

unconventional exponent

$1/\delta = 1/2$ [cf $1/3$ (MF), $1/15$ (2D Ising), $\sim 1/5$ (3D Ising)]

$\gamma = 1, \beta = 1$ scaling relations are satisfied.

Theories for unconventional exponents

triangular-lattice organic compound

unconventional exponents



$1/\delta=1/2$ [cf 1/3 (MF), 1/15 (2D Ising), $\sim 1/5$ (3D Ising)]

$\beta=1$ [cf 1/2 (MF), 1/8 (2D Ising), $\sim 5/16$ (3D Ising)]

(1) Marginally quantum critical region in 2 dimensions

$$\beta=d/2, \quad 1/\delta=d/4$$

(Imada, PRB, 2005)

(2) 2D-Ising universality, but response to energy density

$$\beta=1, \quad 1/\delta=8/15$$

(Papanikolaou et al, PRL, 2008)

Both approaches are phenomenological, and also based on **the assumption that some thermodynamic critical exponent appears in transport singularity.**

(1) Let us calculate electric conductivity directly for a microscopic model near the Mott transition.

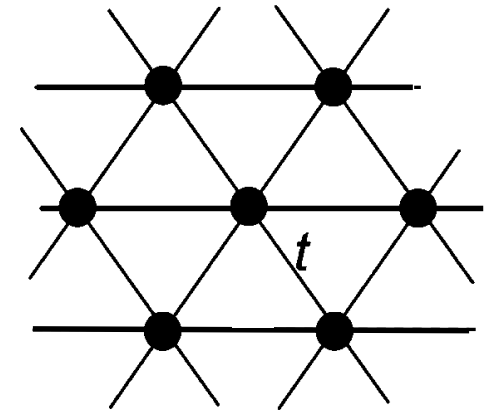
(2) Compare its criticality to the criticality of order parameter.

Model and Method

Model: Hubbard model on triangular lattice

- half filling $n=1$
- $t \sim t' \sim 50$ [meV] (Shimizu, PRL 2003)

$$H = -t \sum_{\langle i,j \rangle, \sigma} (c_{i\sigma}^\dagger c_{j\sigma} + \text{h.c.}) - \mu \sum_{j\sigma} c_{j\sigma}^\dagger c_{j\sigma} + U \sum_j n_{j\uparrow} n_{j\downarrow}$$

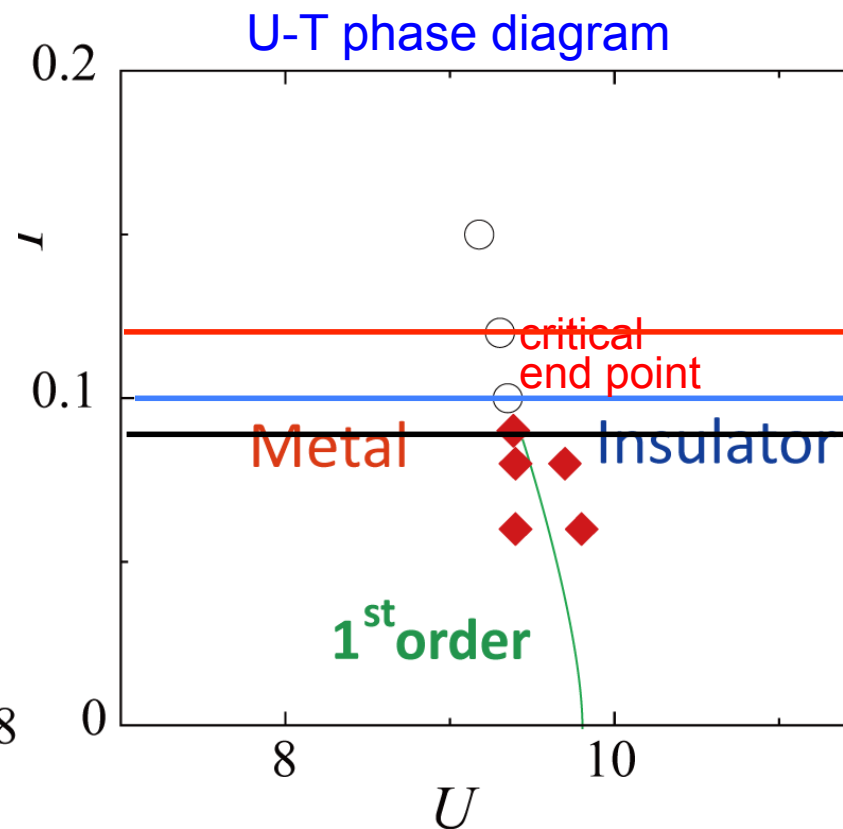
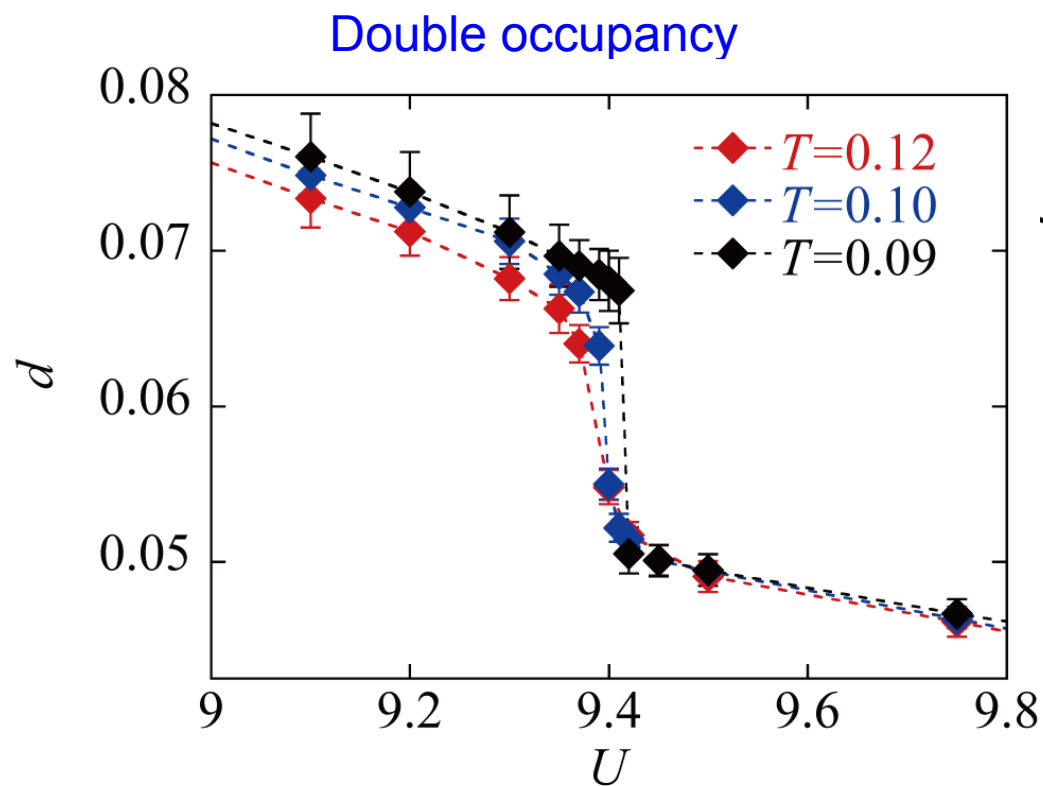


Method: Cluster Dynamical Mean Field Theory (CDMFT)

- 3-site cluster
 - correctly describe Mott transition
 - take into account short-range quantum&thermal fluctuations
- continuous-time quantum Monte Carlo (CTQMC)
 - hybridization expansion
 - effective for large U
- Kubo formula for $\sigma(\omega)$ (inc. vertex corrections inside cluster)

Kotliar
Lichtenstein
Werner
...

U-T Phase diagram



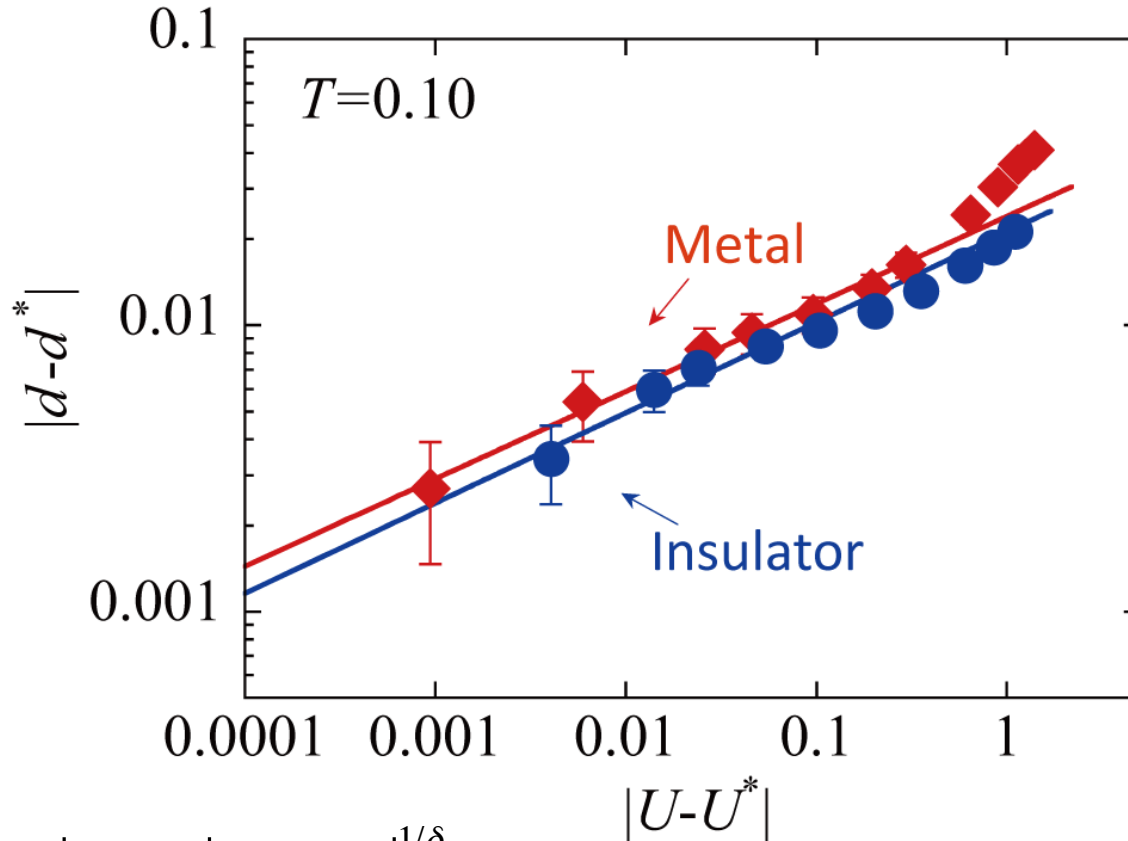
Double occupancy is the order parameter representing thermodynamic criticality of Mott transition.

- ✧ $T/t = 0.09 \Rightarrow$ 1st order transition
- $T/t = 0.12 \Rightarrow$ crossover

K. Kanoda, J. Phys. Soc. Jpn. **75**. 051007 (2006)
 Y. Furukawa (private communication)

Scaling of double occupancy

Double occupancy



$$|d - d^*| \approx A_{\pm} |U - U^*|^{1/\delta_{\pm}}$$

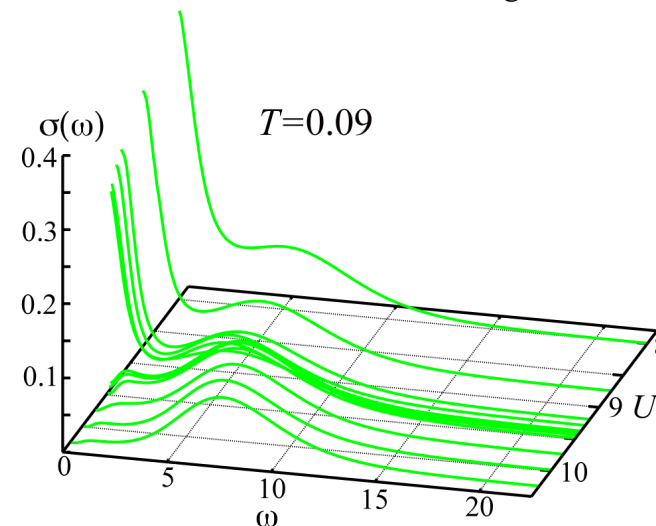
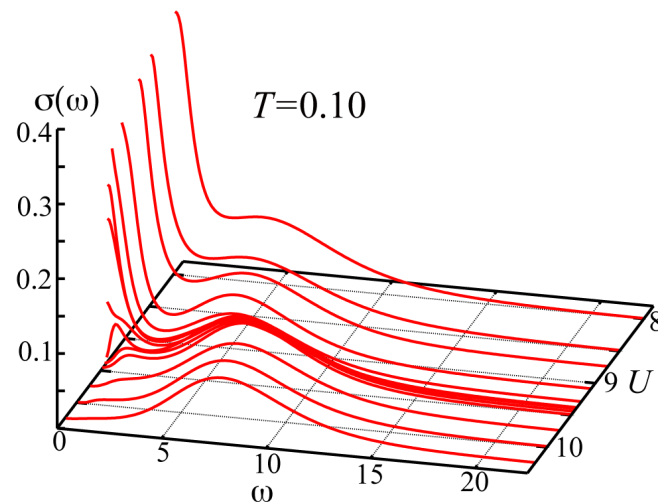
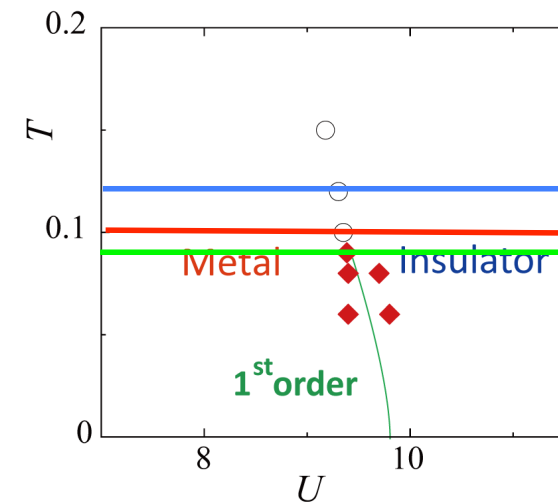
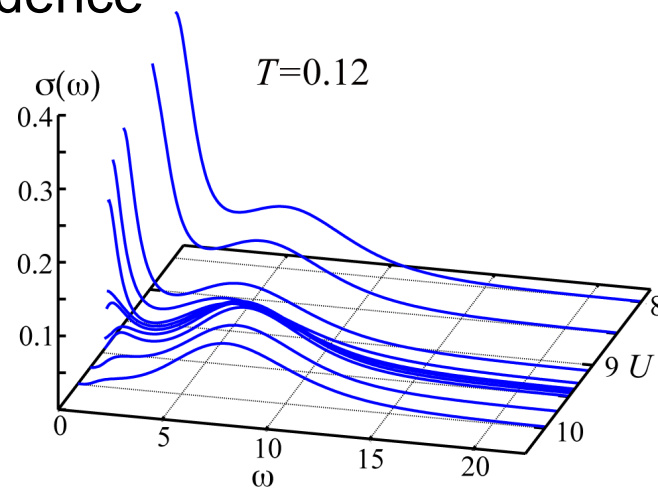
$$1/\delta_- = 0.32 \pm 0.05$$

$$1/\delta_+ = 0.30 \pm 0.04$$

This value is consistent with
the mean-field exponent of Ising order parameter
 $1/\delta=1/3$

Optical conductivity $\sigma(\omega)$

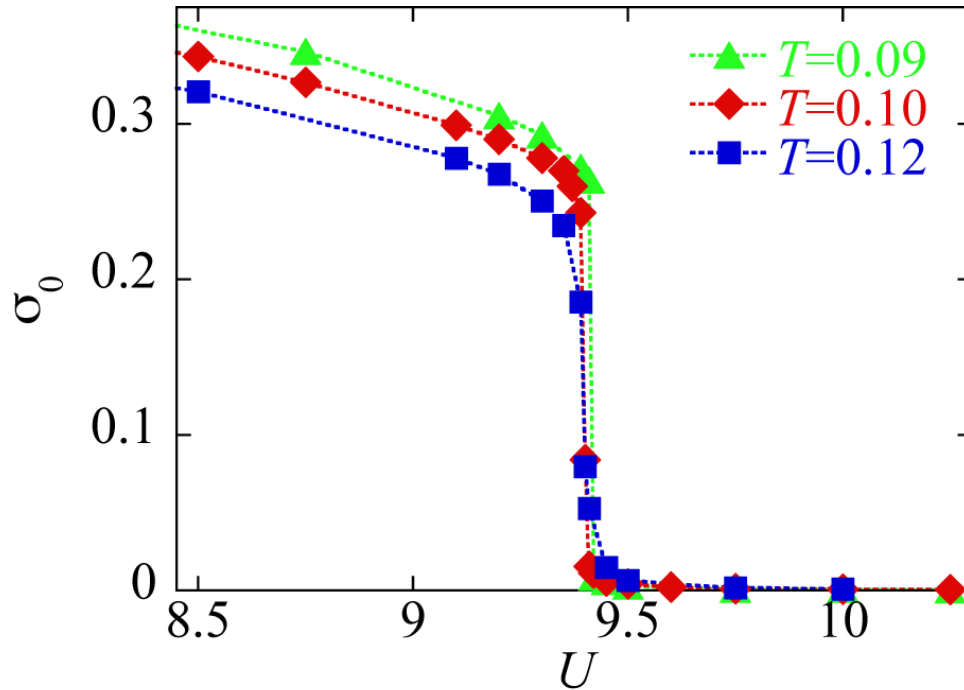
U -dependence



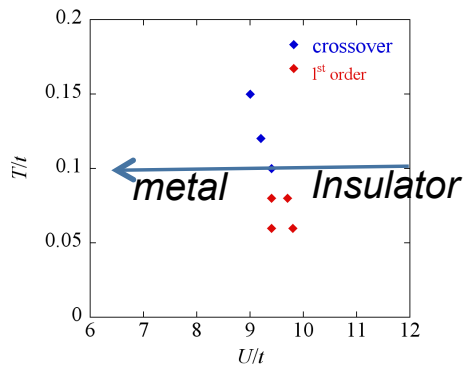
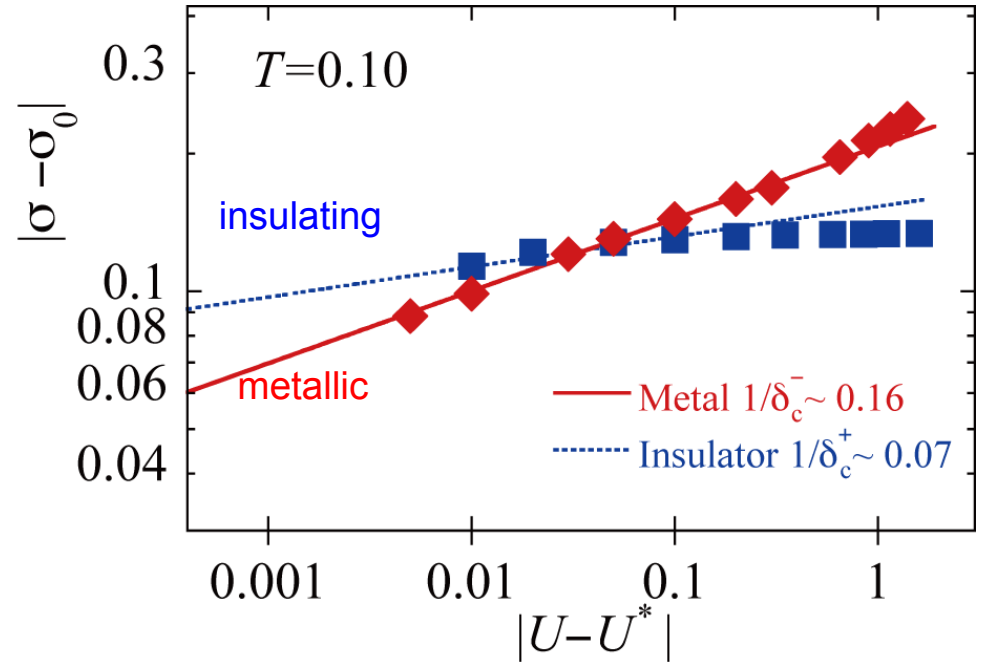
- High- ω incoherent peak is robust and correspond to excitations to the Hubbard bands
- Low- ω Drude peak appears in the metallic region
- U -dependence is continuous but exhibits a singularity around $U/t=9.4$, $T/t=0.10$

DC Conductivity and its Scaling

DC conductivity



$$|\sigma_0 - \sigma_0^*| = A_{\pm} |U - U^*|^{1/\delta_{\pm}}$$



U -dependence of DC conductivity

is continuous,

But the singularity does not have the same exponent on the both sides of the transition.

Choice of scaling variable

Simple choice is the singular part of dc-conductivity:

$$\sigma_0(\delta U) = \sigma_0^{\text{reg}}(\delta U) + \sigma_0^{\text{sing}}(\delta U)$$

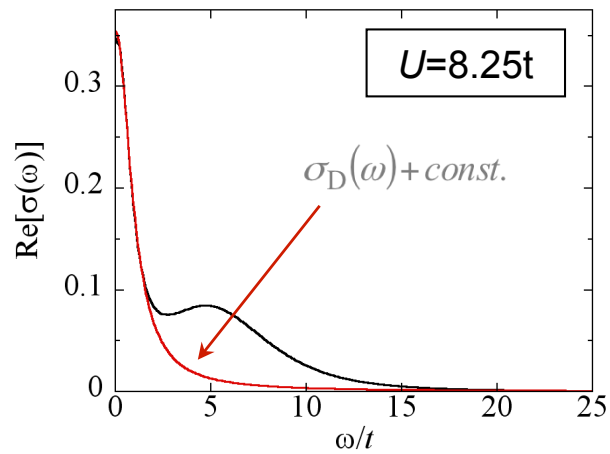
This does not exhibit an expected conventional scaling behavior.

Try another quantity as a scaling variable:

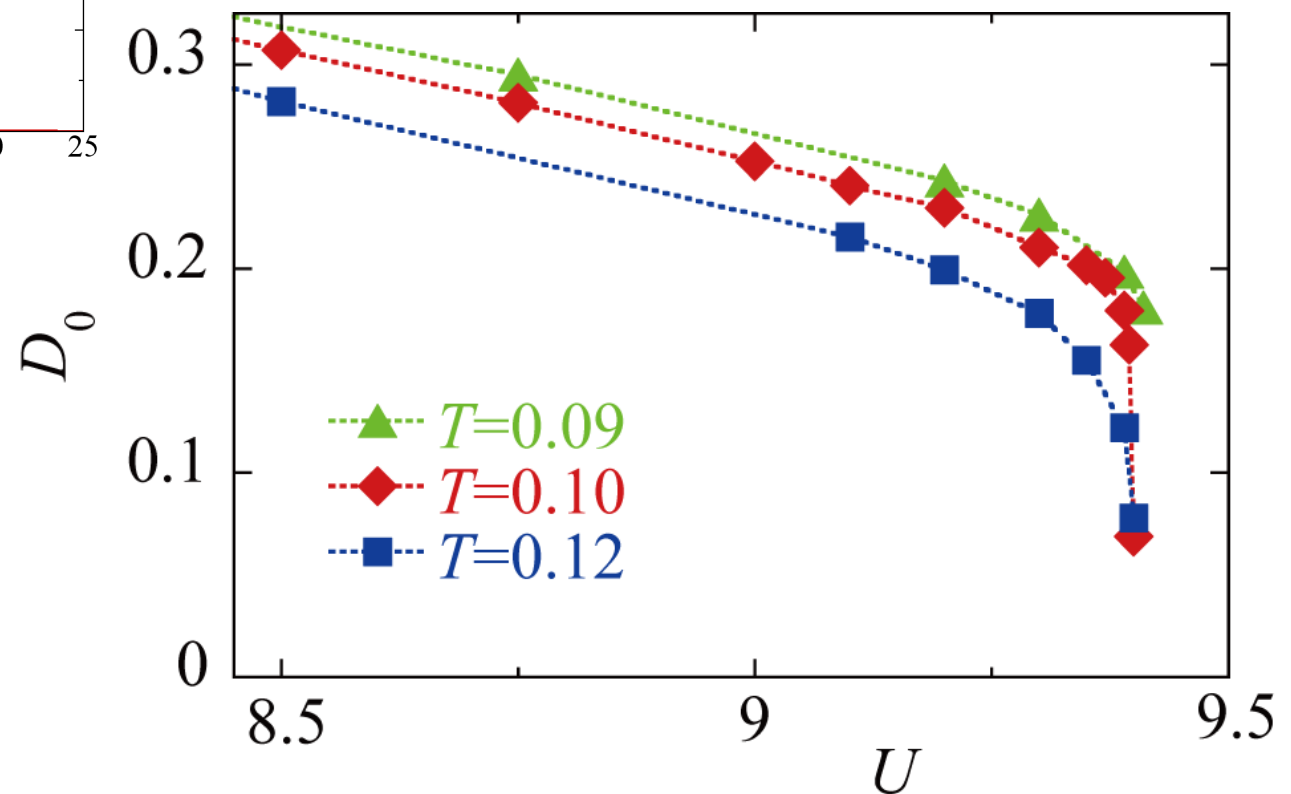
→ the weight of a low-energy peak in $\sigma(\omega)$

Low- ω Peak (metallic side)

➤ Metal side: Drude peak

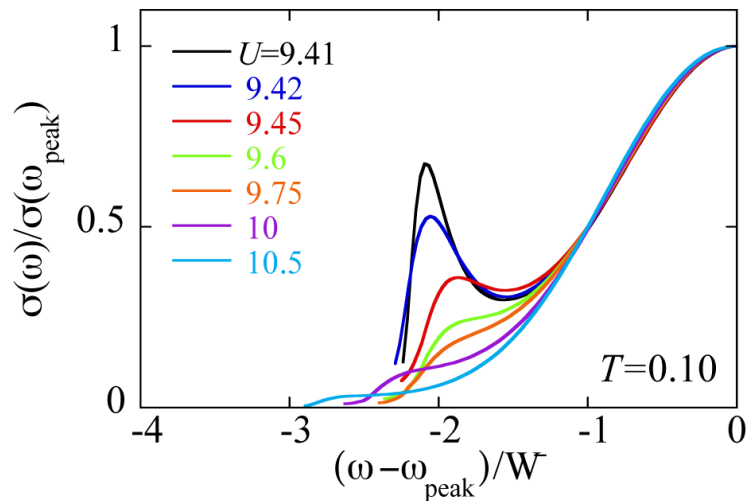


Sharp decrease of the Drude weight with approaching the critical point

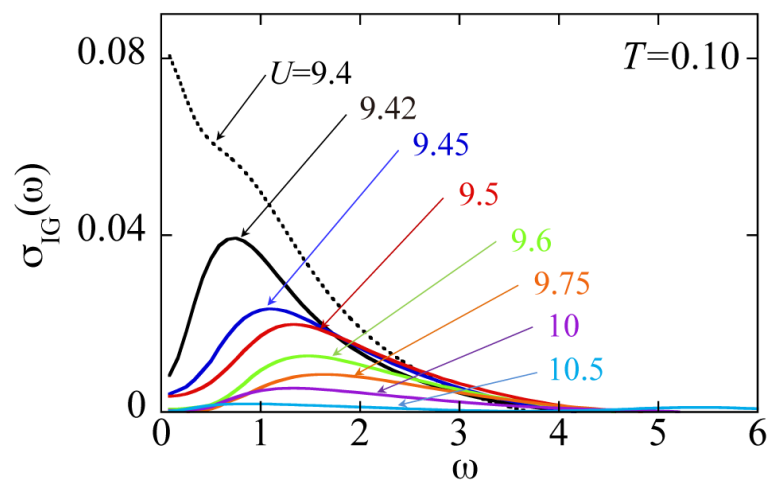


Low- ω Peak (insulating side)

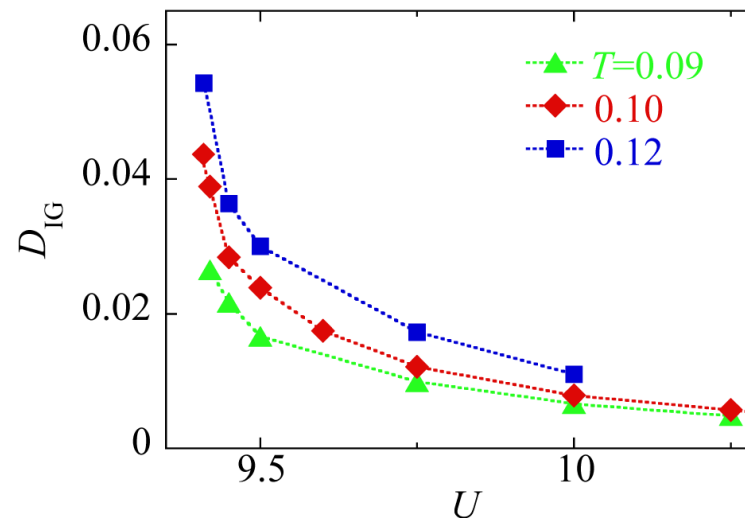
➤ Insulator side: Ingap peak



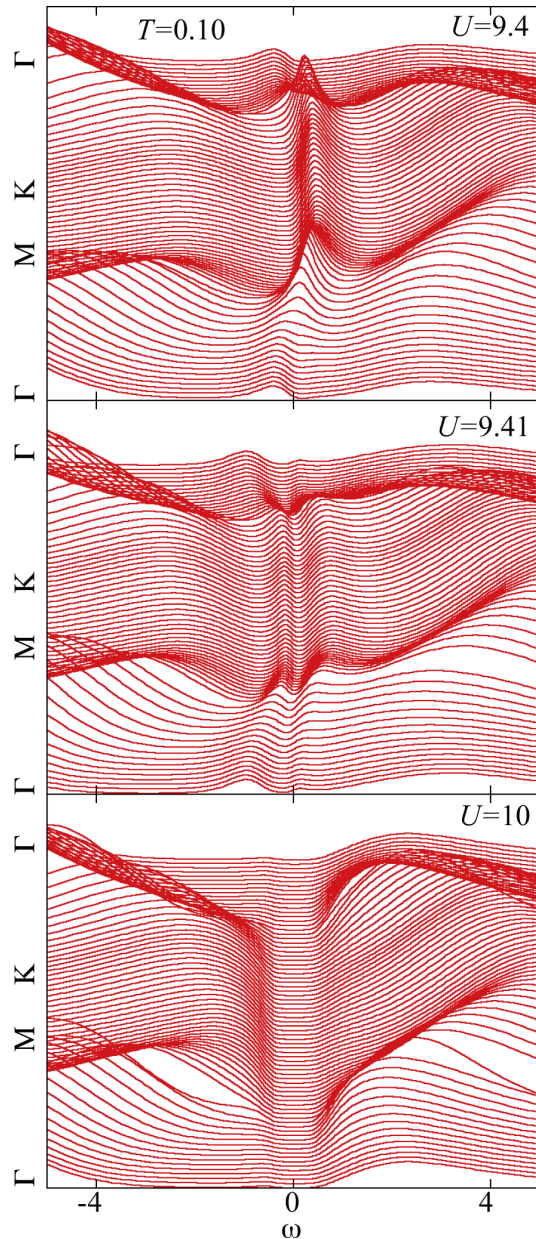
- Within the Hubbard gap, there appears an *ingap peak*.
- Subtract the part of high-energy peak, which is well approximated by Gaussian.
- This ingap peak evolves into the coherent Drude peak on the metallic side.



Weight of the ingap peak



Ingap peak and Electron Spectrum



metallic

heavy quasiparticle band

insulating and near the critical point

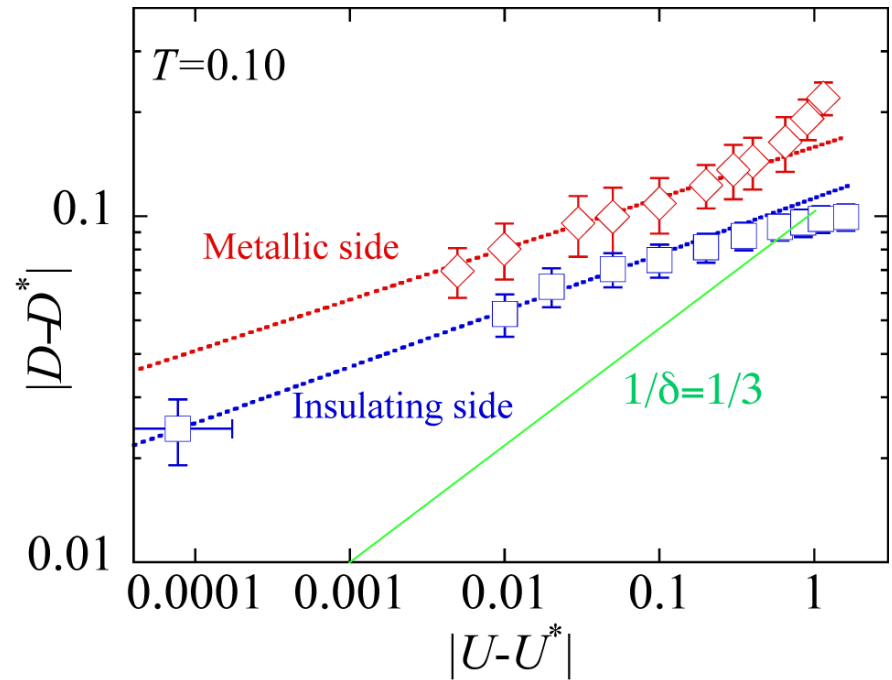
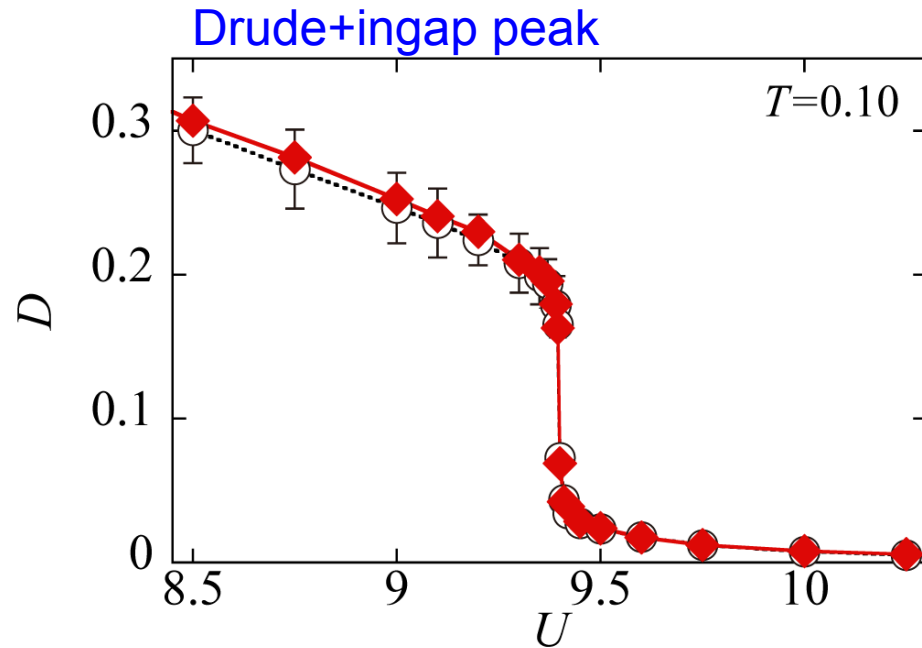
2 small peaks around $\omega=0$

→ ingap peak in $\sigma(\omega)$ correspond to transition between these two

insulating

quasiparticle has disappeared

Scaling analysis of low- ω peaks



$$|D - D^*| \approx A_{\pm} |U - U^*|^{1/\delta_c^{\pm}}$$

$$1/\delta_c^- = 0.15 \pm 0.08$$

$$1/\delta_c^+ = 0.16 \pm 0.05$$

a power-law singularity
with the same exponent
on both sides now

The determined **transport exponent differs from**

Ising universality class

the exponent of order parameter vs. conjugate field at T_c

$1/\delta=1/3$ (MF), $1/15$ (2D Ising), $\sim 1/5$ (3D Ising)

Summary

We have calculated optical conductivity $\sigma(\omega)$ of triangular-lattice Hubbard model. Calculation is performed by Cluster DMFT with Continuous-Time QMC solver for cluster Green's function and includes vertex corrections

- (1) We have observed a critical behavior in optical weight at the Mott transition
- (2) Exponent = ~ 0.15
does not agree with thermodynamic exponent of Ising universality class
[in any dimensions, also exclude simple expectation of mean-field exponent]
- (3) A small peak emerges within the "Mott gap" with approaching critical point on the insulating side (INGAP peak)
- (4) Ingap peak seems to evolve into the Drude peak with $U \downarrow$
- (5) Weight of Drude and ingap peaks are good scaling variable

Outlook

- (A) How to explain the new exponent theoretically?
- (B) Comparison to experimental data. Hubbard model is enough?